International Rectifier

AUTOMOTIVE GRADE

AUIRF6218S AUIRF6218L

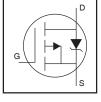
HEXFET® Power MOSFET

Features

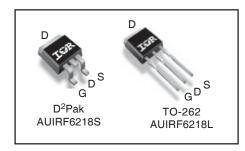
- Advanced Planar Technology
- Low On-Resistance
- P-Channel
- Dynamic dV/dT Rating
- 175°C Operating Temperature
- Fast Switching
- Fully Avalanche Rated
- Repetitive Avalanche Allowed up to Tjmax
- Lead-Free, RoHS Compliant
- Automotive Qualified *

Description

Specifically designed for Automotive applications, this cellular design of HEXFET® Power MOSFETs utilizes the latest processing techniques to achieve low on-resistance per silicon area. This benefit combined with the fast switching speed and rugge-dized device design that HEXFET power MOSFETs are well known for, provides the designer with an extremely efficient and reliable device for use in Automotive and a wide variety of other applications.



V _{(BR)DSS}	-150V
R _{DS(on)} max	150m Ω
I _D	-27A



G	D	S
Gate	Drain	Source

Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (T_A) is 25°C, unless otherwise specified.

	Parameter	Max.	Units
V _{DS}	Drain-to-Source Voltage	-150	V
V _{GS}	Gate-to-Source Voltage	± 20	
I _D @ T _C = 25°C	Continuous Drain Current, V _{GS} @ 10V	-27	А
D @ T _C = 100°C	Continuous Drain Current, V _{GS} @ 10V	-19	
ОМ	Pulsed Drain Current ①	-110	
P _D @ T _C = 25°C	Maximum Power Dissipation	250	W
	Linear Derating Factor	1.6	W/°C
E _{AS}	Single Pulse Avalanche Energy (Thermally Limited) ②	210	mJ
AR	Avalanche Current ①	-16	А
dv/dt	Peak Diode Recovery dv/dt ③	8.2	V/ns
Τ _J	Operating Junction and	-55 to + 175	°C
T _{STG}	Storage Temperature Range		
	Soldering Temperature, for 10 seconds (1.6mm from cas	300	
	Mounting torque, 6-32 or M3 screw	10 lbf•in (1.1N•m)	

Thermal Resistance

	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case ^⑤		0.61	°C/W
$R_{\theta JA}$	Junction-to-Ambient (PCB Mounted, steady state) ©		40	

Static Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
V _{(BR)DSS}	Drain-to-Source Breakdown Voltage	-150			V	$V_{GS} = 0V, I_D = -250\mu A$
$\DeltaV_{(BR)DSS}/\DeltaT_{J}$	Breakdown Voltage Temp. Coefficient		-0.17		V/°C	Reference to 25° C, $I_D = -1$ mA
R _{DS(on)}	Static Drain-to-Source On-Resistance		120	150	mΩ	$V_{GS} = -10V, I_{D} = -16A \ \oplus$
$V_{GS(th)}$	Gate Threshold Voltage	-3.0		-5.0	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
gfs	Forward Transconductance	11			S	$V_{DS} = -50V, I_{D} = -16A$
I _{DSS}	Drain-to-Source Leakage Current			-25	μΑ	$V_{DS} = -120V, V_{GS} = 0V$
				-250		$V_{DS} = -120V$, $V_{GS} = 0V$, $T_{J} = 150$ °C
I _{GSS}	Gate-to-Source Forward Leakage			-100	nA	$V_{GS} = -20V$
	Gate-to-Source Reverse Leakage			100		$V_{GS} = 20V$

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
Qg	Total Gate Charge		71	110		I _D = -16A
Q _{gs}	Gate-to-Source Charge		21		nC	V _{DS} = -120V
Q_{gd}	Gate-to-Drain ("Miller") Charge		32			V _{GS} = -10V ⊕
t _{d(on)}	Turn-On Delay Time		21			$V_{DD} = -75V$
t _r	Rise Time		70		ns	I _D = -16A
t _{d(off)}	Turn-Off Delay Time		35]	$R_G = 3.9\Omega$
t _f	Fall Time		30		1	V _{GS} = -10V ⊕
C _{iss}	Input Capacitance		2210			$V_{GS} = 0V$
Coss	Output Capacitance		370		1	V _{DS} = -25V
C _{rss}	Reverse Transfer Capacitance		89		pF	f = 1.0 MHz
Coss	Output Capacitance		2220		1	$V_{GS} = 0V$, $V_{DS} = -1.0V$, $f = 1.0MHz$
Coss	Output Capacitance		170		1	$V_{GS} = 0V$, $V_{DS} = -120V$, $f = 1.0MHz$
Coss eff.	Effective Output Capacitance		340		1	$V_{GS} = 0V$, $V_{DS} = 0V$ to -120V

Diode Characteristics

	Parameter	Min.	Тур.	Max.	Units	Conditions
IS	Continuous Source Current			-27		MOSFET symbol
	(Body Diode)				Α	showing the
I _{SM}	Pulsed Source Current			-110		integral reverse
	(Body Diode) ①					p-n junction diode.
V_{SD}	Diode Forward Voltage			-1.6	V	$T_J = 25^{\circ}C$, $I_S = -16A$, $V_{GS} = 0V \oplus$
t _{rr}	Reverse Recovery Time		150		ns	$T_J = 25^{\circ}C$, $I_F = -16A$, $V_{DD} = -25V$
Q _{rr}	Reverse Recovery Charge		860		nC	di/dt = -100A/µs

Notes:

- $\ensuremath{\mathbb{O}}$ Repetitive rating; pulse width limited by max. junction temperature.
- ② Starting $T_J = 25^{\circ}C$, L = 1.6mH, $R_G = 25\Omega$, $I_{AS} = -17A$.
- $\label{eq:loss_distance} \mbox{ } \mbox{ } \mbox{I}_{SD} \leq \mbox{-17A}, \mbox{ } \mbox{di/dt} \leq \mbox{-520A/}\mu\mbox{s}, \mbox{ } \mbox{V}_{DD} \leq \mbox{V}_{(BR)DSS}, \mbox{ } \mbox{T}_{J} \leq \mbox{175}^{\circ}\mbox{C}.$
- 4 Pulse width $\leq 300 \mu s$; duty cycle $\leq 2\%$.
- $\ ^{\textcircled{5}}$ R $_{\theta}$ is measured at T $_{J}$ of approximately 90°C.
- ® When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994.

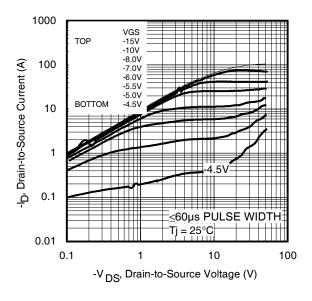
Qualification Information[†]

		Automotive				
		(per AEC-Q101)				
Qualificat	ion Level	Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.				
Maiatura	Sanaitivity Laval	TO-262	N/A			
worsture	Sensitivity Level	D ² Pak MSL1				
	Machine Model	Class M4 (+/- 600V) ^{††}				
		AEC-Q101-002				
	Human Body Model		Class H2 (+/	/- 3000V) ^{††}		
ESD		AEC-Q101-001				
	Charged Device Model		Class C5 (+/	/- 2000V) ^{††}		
		AEC-Q101-005				
RoHS Con	npliant		Ye	s		

[†] Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

3

^{††} Highest passing voltage.



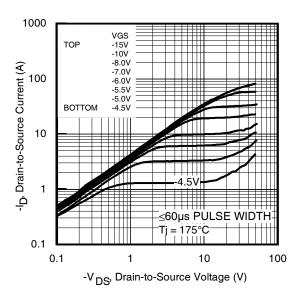
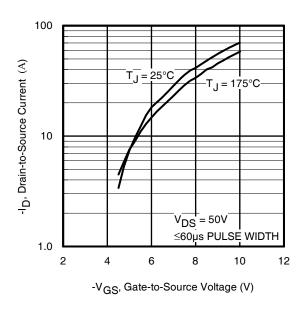


Fig 1. Typical Output Characteristics

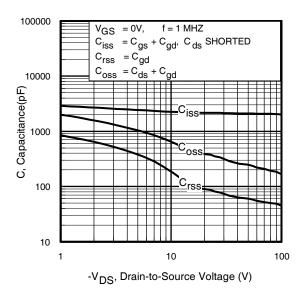
Fig 2. Typical Output Characteristics



2.5

Fig 3. Typical Transfer Characteristics

Fig 4. Normalized On-Resistance vs. Temperature



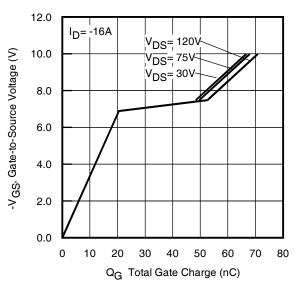
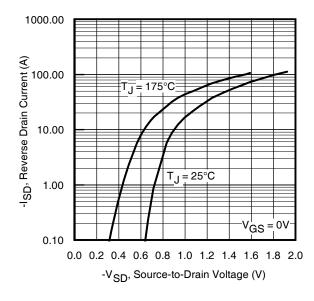


Fig 5. Typical Capacitance vs. Drain-to-Source Voltage

Fig 6. Typical Gate Charge vs. Gate-to-Source Voltage



OPERATION IN THIS AREA

LIMITED BY RDS(on)

100

Tc = 25°C

Tj = 175°C

Single Pulse

1 10 100 1000

-VDS, Drain-to-Source Voltage (V)

Fig 7. Typical Source-Drain Diode Forward Voltage

Fig 8. Maximum Safe Operating Area

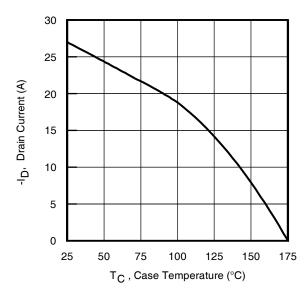


Fig 9. Maximum Drain Current vs. Ambient Temperature

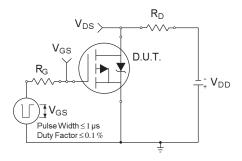


Fig 10a. Switching Time Test Circuit

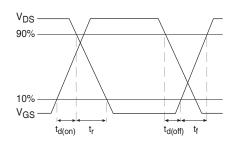


Fig 10b. Switching Time Waveforms

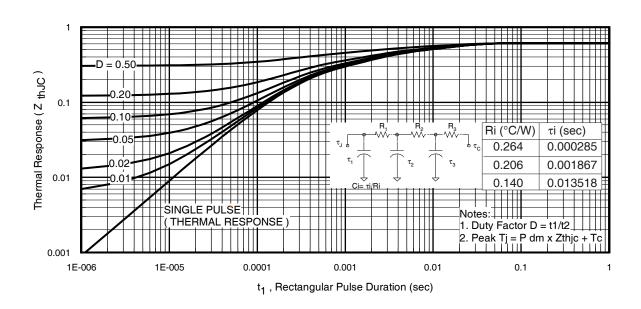
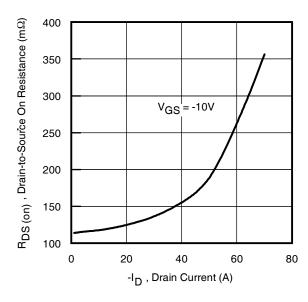


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



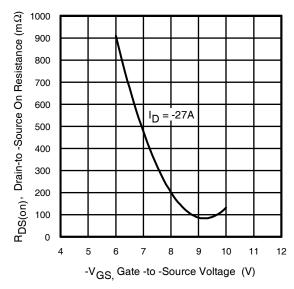


Fig 12. On-Resistance vs. Drain Current

Fig 13. On-Resistance vs. Gate Voltage

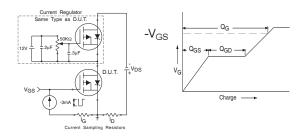


Fig 14a&b. Basic Gate Charge Test Circuit and Waveform

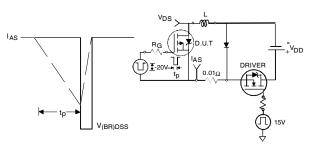


Fig 15a&b. Unclamped Inductive Test circuit and Waveforms

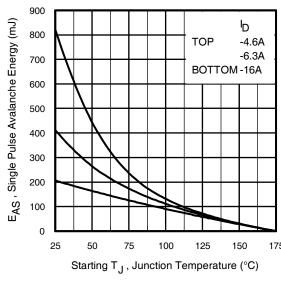
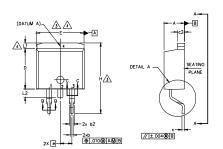


Fig 15c. Maximum Avalanche Energy vs. Drain Current

D²Pak Package Outline

(Dimensions are shown in millimeters (inches))





- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
- 2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].

3. DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.127 [.005"] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY AT DATUM H.

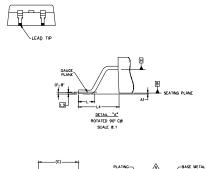
4. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSION E, L1, D1 & E1.

5. DIMENSION 61 AND c1 APPLY TO BASE METAL ONLY.

- 6. DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
- 7. CONTROLLING DIMENSION: INCH.

DIMENSIONS

8. OUTLINE CONFORMS TO JEDEC OUTLINE TO-263AB.

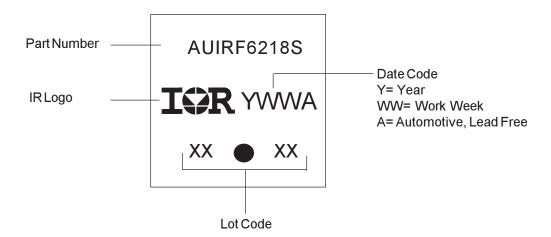


B	MILLIM	MILLIMETERS		HES	T E S
Ľ	MIN.	MAX.	MIN.	MAX.	S
Α	4.06	4,83	.160	.190	
A1	0.00	0.254	.000	.010	
ь	0,51	0.99	.020	.039	
ь1	0.51	0.89	.020	.035	5
b2	1,14	1.78	.045	.070	
b3	1,14	1.73	.045	.068	5
c	0.38	0.74	.015	.029	
c1	0.38	0.58	.015	.023	5
c2	1,14	1.65	.045	.065	
D	8.38	9.65	.330	.380	3
D1	6.86	-	.270		4
E	9.65	10,67	.380	.420	3,4
E1	6.22	-	.245		4
e	2.54	BSC	.100	BSC	
н	14,61	15,88	.575	.625	
L	1,78	2.79	.070	.110	
L1	-	1,65	-	.066	4
L2	1,27	1.78	-	.070	
1					

.188

LEAD ASSIGNMENTS
HEXFET 1. — GATE 2. 4. — DRAIN 3. — SOURCE
IGBIs, COPACK 1.— GATE 2. 4.— COLLECTOR 3.— EMITTER
DIODES 1.— ANODE * 2. 4.— CATHODE 3.— ANODE
* PART DEPENDENT.

D²Pak Part Marking Information

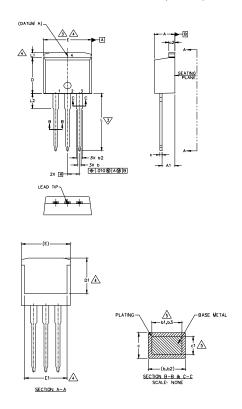


4,78

Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

TO-262 Package Outline

Dimensions are shown in millimeters (inches)



S			N		
M B O L	MILLIM	ETERS	TERS INCHES		
L	MIN.	MAX.	MIN.	MAX.	NOLEN
Α	4.06	4.83	.160	.190	
A1	2.03	3.02	.080	.119	
ь	0.51	0.99	.020	.039	
b1	0.51	0.89	.020	.035	5
ь2	1.14	1.78	.045	.070	
ь3	1.14	1.73	.045	.068	5
С	0.38	0.74	.015	.029	
c1	0.38	0.58	.015	.023	5
c2	1.14	1.65	.045	.065	
D	8.38	9.65	.330	.380	3
D1	6.86	-	.270	-	4
E	9.65	10.67	.380	.420	3,4
E1	6.22	_	.245		4
е	2.54	BSC	.100	BSC	
L	13.46	14.10	.530	.555	
L1	_	1.65	-	.065	4
L2	3.56	3.71	.140	.146	

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2. Collegender of Compone Naturalization (Prices)

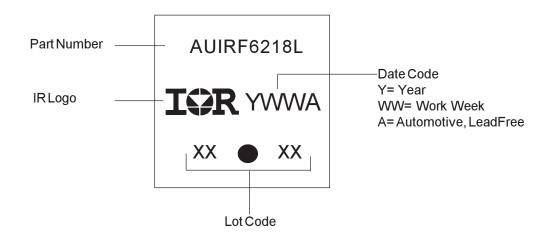
Applications to a Compone Naturalization (Prices)

Applications to Asia Compone Naturalization (Prices)

Application (Prices)

App

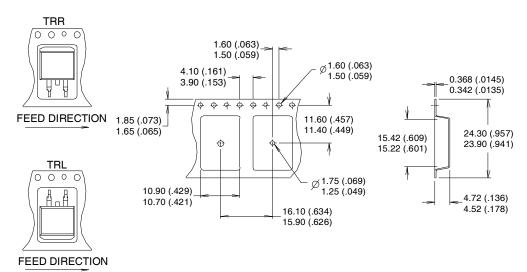
TO-262 Part Marking Information

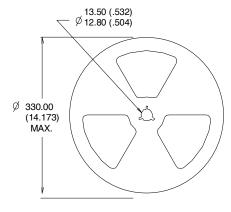


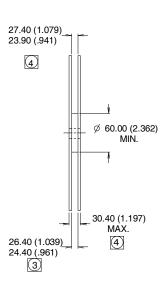
Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

D²Pak Tape & Reel Information

Dimensions are shown in millimeters (inches)







NOTES:

- 1. COMFORMS TO EIA-418.
- CONTROLLING DIMENSION: MILLIMETER.
- 2. CONTROLLING DIMENSION: MILI DIMENSION MEASURED @ HUB.
- 4 INCLUDES FLANGE DISTORTION @ OUTER EDGE.

Ordering Information

Base part number	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIRF6218L	TO-262	Tube	50	AUIRF6218L
AUIRF6218S	D2Pak	Tube	50	AUIRF6218S
		Tape and Reel Left	800	AUIRF6218STRL
		Tape and Reel Right	800	AUIRF6218STRR

AUIRF6218S/L

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Authorized Distribution Brand:

























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